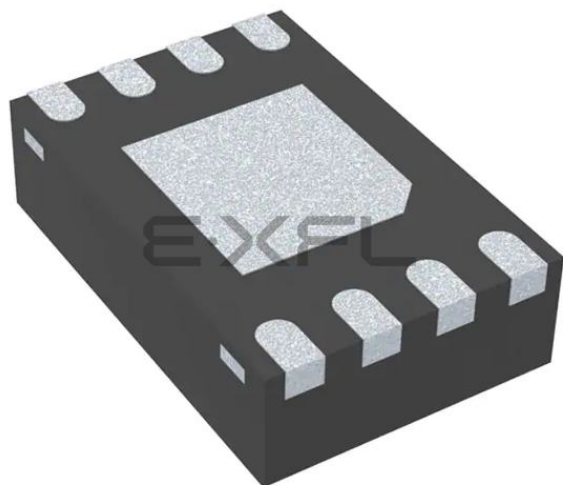




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Details

Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	8MHz
Connectivity	-
Peripherals	POR, WDT
Number of I/O	5
Program Memory Size	1.5KB (1K x 12)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	41 x 8
Voltage - Supply (Vcc/Vdd)	2V ~ 5.5V
Data Converters	-
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	8-VDFN Exposed Pad
Supplier Device Package	8-DFN (2x3)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic12f519t-i-mc

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- Microchip products meet the specification contained in their particular Microchip Data Sheet.
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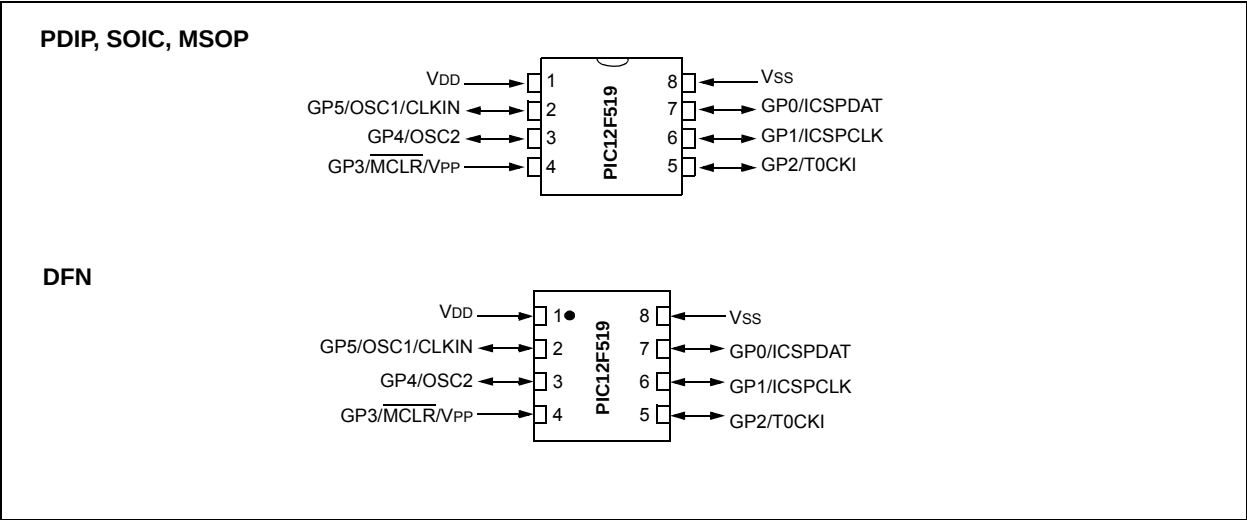
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PIC12F519

FIGURE 1: PIC12F519 8-PIN PDIP, SOIC, MSOP, 2X3 DFN DIAGRAM



Device	Program Memory	Data Memory		I/O	Timers 8-bit
	Flash (words)	SRAM (bytes)	Flash (bytes)		
PIC12F519	1024	41	64	6	1

PIC12F519

NOTES:

TABLE 3-2: PIC12F519 PINOUT DESCRIPTION

Name	Function	Type	Input Type	Output Type	Description
GP0/ICSPDAT	GP0	I/O	TTL	CMOS	Bidirectional I/O port with weak pull-up
	ICSPDAT	I/O	ST	CMOS	ICSP™ mode Schmitt Trigger
GP1/ICSPCLK	GP1	I/O	TTL	CMOS	Bidirectional I/O port with weak pull-up
	ICSPCLK	I	ST	—	ICSP™ mode Schmitt Trigger
GP2/T0CKI	GP2	I/O	TTL	CMOS	Bidirectional I/O port
	T0CKI	I	ST	—	Timer0 clock input
GP3/MCLR/VPP	GP3	I	TTL	—	Standard TTL input with weak pull-up
	MCLR	I	ST	—	MCLR input (Weak pull-up always enabled in this mode)
	VPP	I	High Voltage	—	Test mode high voltage pin
GP4/OSC2	GP4	I/O	TTL	CMOS	Bidirectional I/O port
	OSC2	O	—	XTAL	XTAL oscillator output pin
GP5/OSC1/CLKIN	GP5	I/O	TTL	CMOS	Bidirectional I/O port
	OSC1	I	XTAL	—	XTAL oscillator input pin
	CLKIN	I	ST	—	EXTRC Schmitt Trigger input
VDD	VDD	P	—	—	Positive supply for logic and I/O pins
VSS	VSS	P	—	—	Ground reference for logic and I/O pins

Legend: I = Input, O = Output, I/O = Input/Output, P = Power, — = Not Used, TTL = TTL input, ST = Schmitt Trigger input, AN = Analog Voltage

PIC12F519

3.1 Clocking Scheme/Instruction Cycle

The clock input (OSC1/CLKIN pin) is internally divided by four to generate four non-overlapping quadrature clocks, namely Q1, Q2, Q3 and Q4. Internally, the PC is incremented every Q1 and the instruction is fetched from program memory and latched into the instruction register in Q4. It is decoded and executed during the following Q1 through Q4. The clocks and instruction execution flow is shown in Figure 3-2 and Example 3-1.

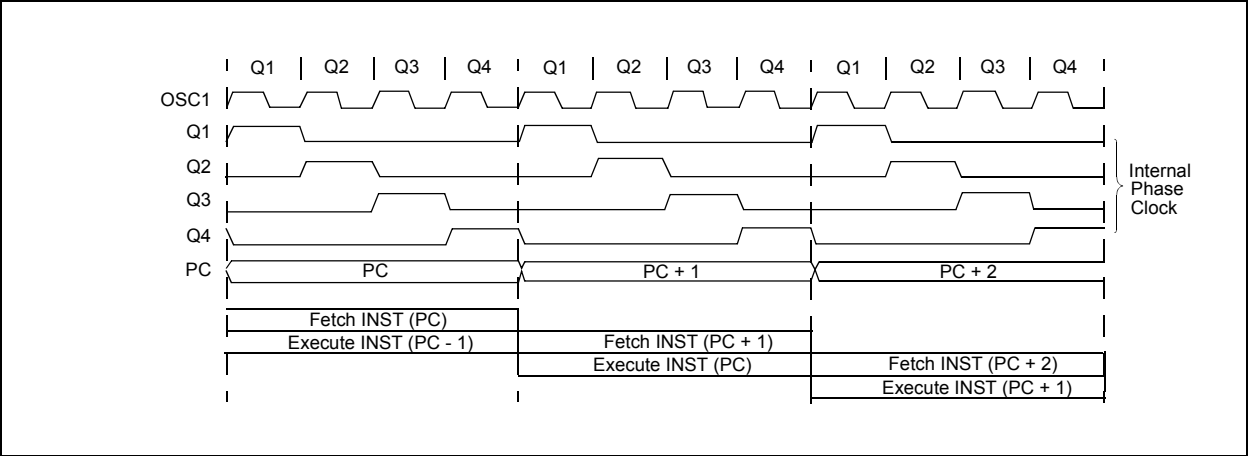
3.2 Instruction Flow/Pipelining

An instruction cycle consists of four Q cycles (Q1, Q2, Q3 and Q4). The instruction fetch and execute are pipelined such that fetch takes one instruction cycle, while decode and execute take another instruction cycle. However, due to the pipelining, each instruction effectively executes in one cycle. If an instruction causes the PC to change (e.g., GOTO), then two cycles are required to complete the instruction (Example 3-1).

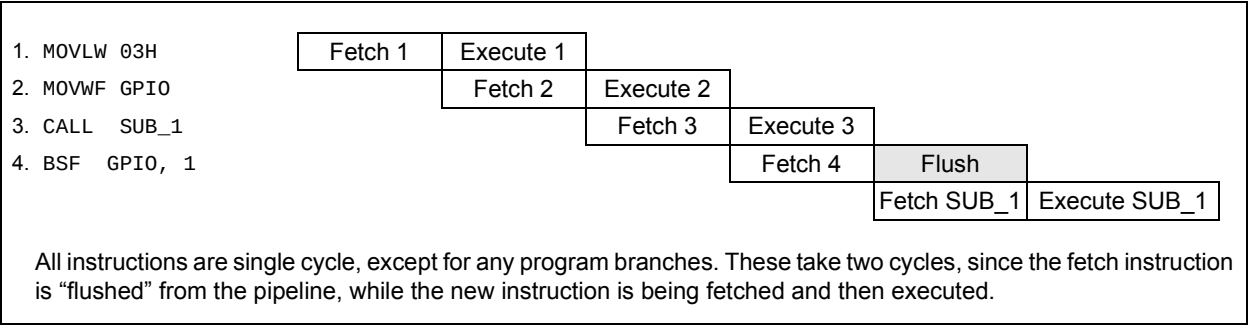
A fetch cycle begins with the PC incrementing in Q1.

In the execution cycle, the fetched instruction is latched into the Instruction Register (IR) in cycle Q1. This instruction is then decoded and executed during the Q2, Q3 and Q4 cycles. Data memory is read during Q2 (operand read) and written during Q4 (destination write).

FIGURE 3-2: CLOCK/INSTRUCTION CYCLE



EXAMPLE 3-1: INSTRUCTION PIPELINE FLOW



PIC12F519

4.5 OSCCAL Register

The Oscillator Calibration (OSCCAL) register is used to calibrate the 8 MHz internal oscillator macro. It contains 7 bits of calibration that uses a two's complement scheme for controlling the oscillator speed. See Register 4-3 for details.

REGISTER 4-3: OSCCAL: OSCILLATOR CALIBRATION REGISTER

R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	U-0
CAL6	CAL5	CAL4	CAL3	CAL2	CAL1	CAL0	—
bit 7							bit 0

Legend:

R = Readable bit

W = Writable bit

U = Unimplemented bit, read as '0'

-n = Value at POR

'1' = Bit is set

'0' = Bit is cleared

x = Bit is unknown

bit 7-1 **CAL<6:0>**: Oscillator Calibration bits

0111111 = Maximum frequency

•

•

•

0000001

0000000 = Center frequency

1111111

•

•

•

1000000 =Minimum frequency

bit 0 **Unimplemented:** Read as '0'

4.8 Indirect Data Addressing: INDF and FSR Registers

The INDF register is not a physical register. Addressing INDF actually addresses the register whose address is contained in the FSR register (FSR is a *pointer*). This is indirect addressing.

Reading INDF itself indirectly (FSR = 0) will produce 00h. Writing to the INDF register indirectly results in a no-operation (although Status bits may be affected).

The FSR is an 8-bit wide register. It is used in conjunction with the INDF Register to indirectly address the data memory area.

The FSR<4:0> bits are used to select data memory addresses 00h to 1Fh.

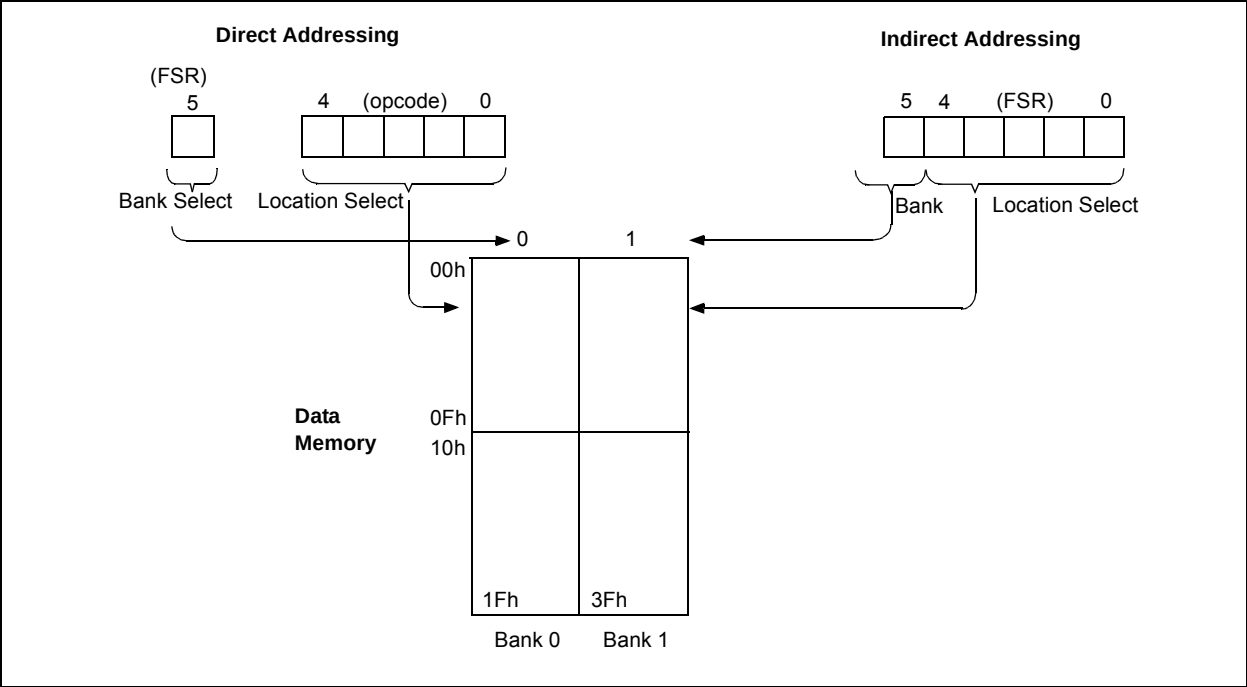
FSR<5> is used to select between banks (0 = Bank 0, 1 = Bank 1).

FSR<7:6> are unimplemented and read as '11'.

EXAMPLE 4-1: HOW TO CLEAR RAM USING INDIRECT ADDRESSING

```
MOV LW 0x10 ;initialize pointer
MOV W FSR ;to RAM
NEXT CLR F INDF ;clear INDF
;register
INCF FSR,F ;inc pointer
BTFSC FSR,4 ;all done?
GOTO NEXT ;NO, clear next
CONTINUE
: ;YES, continue
:
```

FIGURE 4-4: DIRECT/INDIRECT ADDRESSING



PIC12F519

REGISTER 8-1: CONFIG: CONFIGURATION WORD REGISTER⁽¹⁾

—	CPDF	IOSCFS	MCLRE	CP	WDTE	FOSC1	FOSC0
bit 7							bit 0

- bit 7 **Unimplemented:** Read as '1'
- bit 6 **CPDF:** Code Protection bit - Flash Data Memory
1 = Code protection off
0 = Code protection on
- bit 5 **IOSCFS:** Internal Oscillator Frequency Select bit
1 = 8 MHz INTOSC frequency
0 = 4 MHz INTOSC frequency
- bit 4 **MCLRE:** Master Clear Enable bit
1 = GP3/MCLR pin functions as MCLR
0 = GP3/MCLR pin functions as GP3, MCLR internally tied to VDD
- bit 3 **CP:** Code Protection bit - User Program Memory
1 = Code protection off
0 = Code protection on
- bit 2 **WDTE:** Watchdog Timer Enable bit
1 = WDT enabled
0 = WDT disabled
- bit 1-0 **FOSC<1:0>:** Oscillator Selection bits
00 = LP oscillator with 18 ms DRT⁽²⁾
01 = XT oscillator with 18 ms DRT⁽²⁾
10 = INTOSC with 1 ms DRT⁽²⁾
11 = EXTRC with 1 ms DRT⁽²⁾

Note 1: Refer to the "PIC12F519 Memory Programming Specification", DS41316 to determine how to program/erase the Configuration Word.

- 2:** DRT length (18 ms or 1 ms) is a function of clock mode selection. It is the responsibility of the application designer to ensure the use of either 18 ms (nominal) DRT or the 1 ms (nominal) DRT will result in acceptable operation. Refer to Figure 11-1 and Table 11-2 for VDD rise time and stability requirements for this mode of operation.

8.2 Oscillator Configurations

8.2.1 OSCILLATOR TYPES

The PIC12F519 device can be operated in up to four different oscillator modes. The user can program using the Configuration bits (FOSC<1:0>), to select one of these modes:

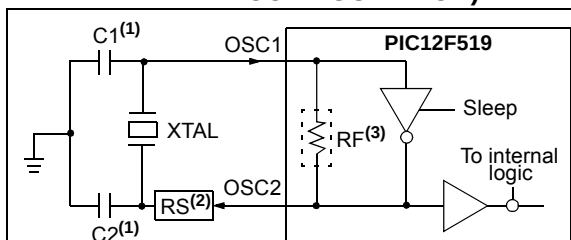
- LP: Low-Power Crystal
- XT: Crystal/Resonator
- INTRC: Internal 4 MHz or 8 MHz Oscillator
- EXTRC: External Resistor/Capacitor

8.2.2 CRYSTAL OSCILLATOR/CERAMIC RESONATORS

In XT or LP modes, a crystal or ceramic resonator is connected to the (GP5)/OSC1/(CLKIN) and (GP4)/OSC2 pins to establish oscillation (Figure 8-1). The PIC12F519 oscillator designs require the use of a parallel cut crystal. Use of a series cut crystal may give a frequency out of the crystal manufacturers specifications. When in XT or LP modes, the device can have an external clock source drive the (GP5)/OSC1/(CLKIN) pin (Figure 8-2). When the part is used in this fashion, the output drive levels on the OSC2 pin are very weak. This pin should be left open and unloaded. Also when using this mode, the external clock should observe the frequency limits for the clock mode chosen (XT or LP).

Note 1: The user should verify that the device oscillator starts and performs as expected. Adjusting the loading capacitor values and/or the Oscillator mode may be required.

FIGURE 8-1: CRYSTAL OPERATION (OR CERAMIC RESONATOR) (XT OR LP OSC CONFIGURATION)



- Note 1:** See Capacitor Selection tables for recommended values of C1 and C2.
- Note 2:** A series resistor (RS) may be required for AT strip cut crystals.
- Note 3:** RF approx. value = 10 MΩ.

FIGURE 8-2: EXTERNAL CLOCK INPUT OPERATION (XT OR LP OSC CONFIGURATION)

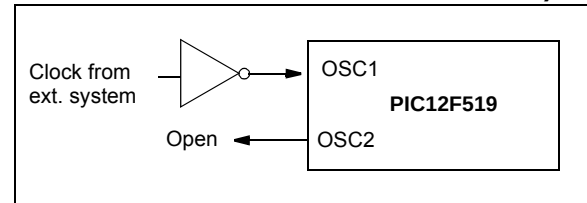


TABLE 8-1: CAPACITOR SELECTION FOR CERAMIC RESONATORS

Osc Type	Resonator Freq.	Cap. Range C1	Cap. Range C2
XT	4.0 MHz	30 pF	30 pF

Note: Component values shown are for design guidance only. Since each resonator has its own characteristics, the user should consult the resonator manufacturer for appropriate values of external components.

TABLE 8-2: CAPACITOR SELECTION FOR CRYSTAL OSCILLATOR – PIC12F519(2)

Osc Type	Resonator Freq.	Cap. Range C1	Cap. Range C2
LP	32 kHz ⁽¹⁾	15 pF	15 pF
XT	200 kHz	47-68 pF	47-68 pF
	1 MHz	15 pF	15 pF
	4 MHz	15 pF	15 pF

- Note 1:** For VDD > 4.5V, C1 = C2 ≈ 30 pF is recommended.
- Note 2:** Component values shown are for design guidance only. Rs may be required to avoid overdriving crystals with low drive level specification. Since each crystal has its own characteristics, the user should consult the crystal manufacturer for appropriate values of external components.

FIGURE 8-7: SIMPLIFIED BLOCK DIAGRAM OF ON-CHIP RESET CIRCUIT

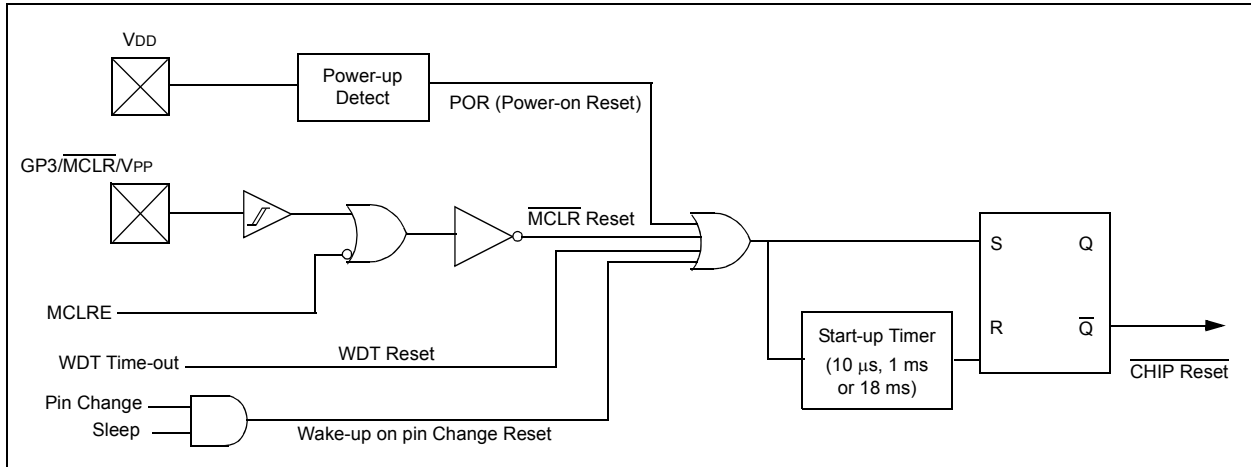


FIGURE 8-8: TIME-OUT SEQUENCE ON POWER-UP ($\overline{\text{MCLR}}$ PULLED LOW)

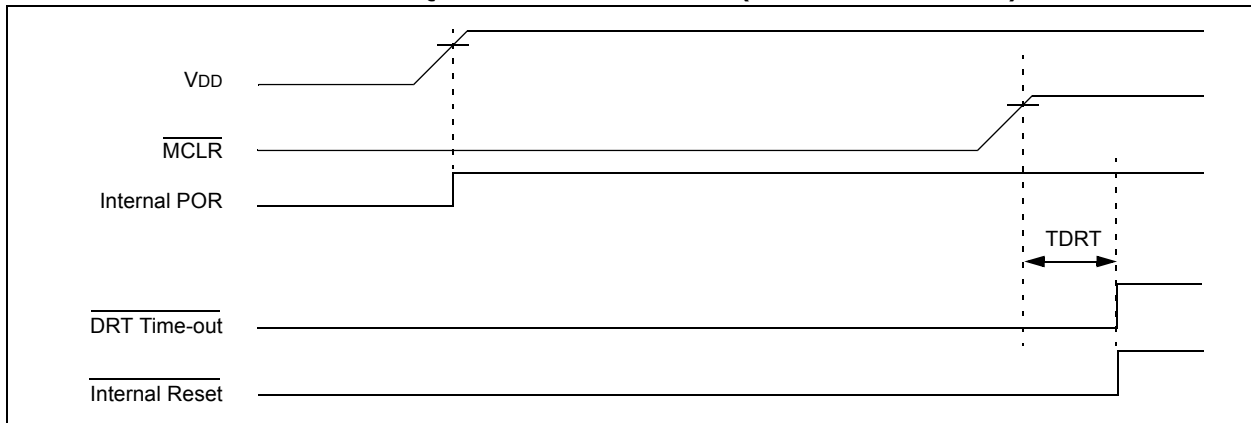
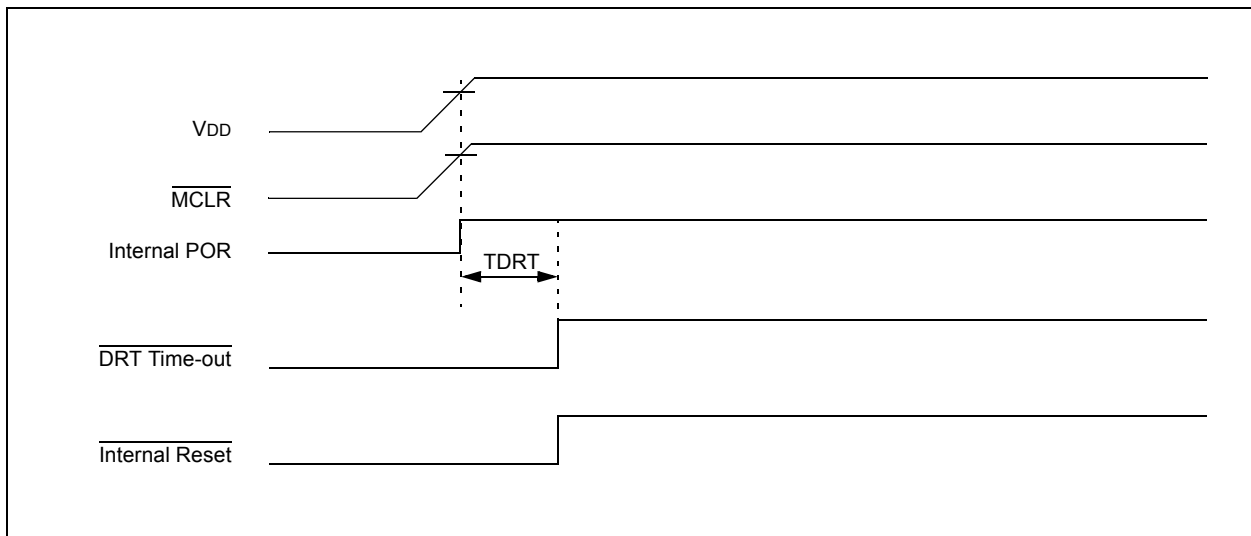


FIGURE 8-9: TIME-OUT SEQUENCE ON POWER-UP ($\overline{\text{MCLR}}$ TIED TO V_{DD}): FAST V_{DD} RISE TIME



10.7 MPLAB ICE 2000 High-Performance In-Circuit Emulator

The MPLAB ICE 2000 In-Circuit Emulator is intended to provide the product development engineer with a complete microcontroller design tool set for PIC microcontrollers. Software control of the MPLAB ICE 2000 In-Circuit Emulator is advanced by the MPLAB Integrated Development Environment, which allows editing, building, downloading and source debugging from a single environment.

The MPLAB ICE 2000 is a full-featured emulator system with enhanced trace, trigger and data monitoring features. Interchangeable processor modules allow the system to be easily reconfigured for emulation of different processors. The architecture of the MPLAB ICE 2000 In-Circuit Emulator allows expansion to support new PIC microcontrollers.

The MPLAB ICE 2000 In-Circuit Emulator system has been designed as a real-time emulation system with advanced features that are typically found on more expensive development tools. The PC platform and Microsoft® Windows® 32-bit operating system were chosen to best make these features available in a simple, unified application.

10.8 MPLAB REAL ICE In-Circuit Emulator System

MPLAB REAL ICE In-Circuit Emulator System is Microchip's next generation high-speed emulator for Microchip Flash DSC® and MCU devices. It debugs and programs PIC® and dsPIC® Flash microcontrollers with the easy-to-use, powerful graphical user interface of the MPLAB Integrated Development Environment (IDE), included with each kit.

The MPLAB REAL ICE probe is connected to the design engineer's PC using a high-speed USB 2.0 interface and is connected to the target with either a connector compatible with the popular MPLAB ICD 2 system (RJ11) or with the new high speed, noise tolerant, low-voltage differential signal (LVDS) interconnection (CAT5).

MPLAB REAL ICE is field upgradeable through future firmware downloads in MPLAB IDE. In upcoming releases of MPLAB IDE, new devices will be supported, and new features will be added, such as software breakpoints and assembly code trace. MPLAB REAL ICE offers significant advantages over competitive emulators including low-cost, full-speed emulation, real-time variable watches, trace analysis, complex breakpoints, a ruggedized probe interface and long (up to three meters) interconnection cables.

10.9 MPLAB ICD 2 In-Circuit Debugger

Microchip's In-Circuit Debugger, MPLAB ICD 2, is a powerful, low-cost, run-time development tool, connecting to the host PC via an RS-232 or high-speed USB interface. This tool is based on the Flash PIC MCUs and can be used to develop for these and other PIC MCUs and dsPIC DSCs. The MPLAB ICD 2 utilizes the in-circuit debugging capability built into the Flash devices. This feature, along with Microchip's In-Circuit Serial Programming™ (ICSP™) protocol, offers cost-effective, in-circuit Flash debugging from the graphical user interface of the MPLAB Integrated Development Environment. This enables a designer to develop and debug source code by setting breakpoints, single stepping and watching variables, and CPU status and peripheral registers. Running at full speed enables testing hardware and applications in real time. MPLAB ICD 2 also serves as a development programmer for selected PIC devices.

10.10 MPLAB PM3 Device Programmer

The MPLAB PM3 Device Programmer is a universal, CE compliant device programmer with programmable voltage verification at VDDMIN and VDDMAX for maximum reliability. It features a large LCD display (128 x 64) for menus and error messages and a modular, detachable socket assembly to support various package types. The ICSP™ cable assembly is included as a standard item. In Stand-Alone mode, the MPLAB PM3 Device Programmer can read, verify and program PIC devices without a PC connection. It can also set code protection in this mode. The MPLAB PM3 connects to the host PC via an RS-232 or USB cable. The MPLAB PM3 has high-speed communications and optimized algorithms for quick programming of large memory devices and incorporates an SD/MMC card for file storage and secure data applications.

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TABLE 11-2: DC CHARACTERISTICS: PIC12F519 (Extended)

DC CHARACTERISTICS			Standard Operating Conditions (unless otherwise specified) Operating Temperature $-40^{\circ}\text{C} \leq T_A \leq +125^{\circ}\text{C}$ (extended)				
Param No.	Sym.	Characteristic	Min.	Typ ⁽¹⁾	Max.	Units	Conditions
D001	VDD	Supply Voltage	2.0		5.5	V	See Figure 11-1
D002	VDR	RAM Data Retention Voltage ⁽²⁾	—	1.5*	—	V	Device in Sleep mode
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	—	VSS	—	V	See Section 8.4 “Power-on Reset (POR)” for details
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	—	—	V/ms	See Section 8.4 “Power-on Reset (POR)” for details
D005	IDDP	Supply Current During Prog/Erase.	—	250*	—	μA	
D010	IDD	Supply Current ^(3,4)	—	175	250	μA	FOSC = 4 MHz, VDD = 2.0V
			—	400	700	mA	FOSC = 4 MHz, VDD = 5.0V
			—	250	400	μA	FOSC = 8 MHz, VDD = 2.0V
			—	0.75	1.2	mA	FOSC = 8 MHz, VDD = 5.0V
D020	IPD	Power-down Current ⁽⁵⁾	—	0.1	9.0	μA	VDD = 2.0V
			—	0.35	15.0	μA	VDD = 5.0V
D022	IWDT	WDT Current	—	1.0	18	μA	VDD = 2.0V
			—	7.0	22	μA	VDD = 5.0V

* These parameters are characterized but not tested.

- Note 1:** Data in the Typical (“Typ”) column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- 2:** This is the limit to which VDD can be lowered in Sleep mode without losing RAM data.
- 3:** The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
- 4:** The test conditions for all IDD measurements in active operation mode are:
OSC1 = external square wave, from rail-to-rail for external clock modes; all I/O pins tri-stated, pulled to VSS, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
- 5:** For standby current measurements, the conditions are the same as IDD, except that the device is in Sleep mode. If a module current is listed, the current is for that specific module enabled and the device in Sleep.

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TABLE 11-4: PULL-UP RESISTOR RANGES

V _{DD} (Volts)	Temperature (°C)	Min.	Typ.	Max.	Units
GP0/GP1					
2.0	–40	73K	105K	186K	Ω
	25	73K	113K	187K	Ω
	85	82K	123K	190K	Ω
	125	86K	132K	190K	Ω
5.5	–40	15K	21K	33K	Ω
	25	15K	22K	34K	Ω
	85	19K	26K	35K	Ω
	125	23K	29K	35K	Ω
GP3					
2.0	–40	63K	81K	96K	Ω
	25	77K	93K	116K	Ω
	85	82K	96K	116K	Ω
	125	86K	100K	119K	Ω
5.5	–40	16K	20K	22K	Ω
	25	16K	21K	23K	Ω
	85	24K	25K	28K	Ω
	125	26K	27K	29K	Ω

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TABLE 11-10: TIMER0 CLOCK REQUIREMENTS

AC CHARACTERISTICS				Standard Operating Conditions (unless otherwise specified) Operating Temperature $-40^{\circ}\text{C} \leq T_A \leq +85^{\circ}\text{C}$ (industrial) $-40^{\circ}\text{C} \leq T_A \leq +125^{\circ}\text{C}$ (extended) Operating Voltage V_{DD} range is described in Section TABLE 11-3: “DC CHARACTERISTICS: PIC12F519 (Industrial, Extended)”				
Param No.	Sym.	Characteristic		Min.	Typ ⁽¹⁾	Max.	Units	Conditions
40	Tt0H	T0CKI High Pulse Width	No Prescaler	$0.5 T_{CY} + 20^*$	—	—	ns	
			With Prescaler	10^*	—	—	ns	
41	Tt0L	T0CKI Low Pulse Width	No Prescaler	$0.5 T_{CY} + 20^*$	—	—	ns	
			With Prescaler	10^*	—	—	ns	
42	Tt0P	T0CKI Period		$20 \text{ or } T_{CY} + 40^* N$	—	—	ns	Whichever is greater. $N = \text{Prescale Value}$ (1, 2, 4, ..., 256)

* These parameters are characterized but not tested.

Note 1: Data in the Typical (“Typ”) column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

TABLE 11-11: FLASH DATA MEMORY WRITE/ERASE REQUIREMENTS

AC CHARACTERISTICS			Standard Operating Conditions (unless otherwise specified) Operating Temperature $-40^{\circ}\text{C} \leq T_A \leq +85^{\circ}\text{C}$ (industrial) $-40^{\circ}\text{C} \leq T_A \leq +125^{\circ}\text{C}$ (extended) Operating Voltage V_{DD} range is described in Section TABLE 11-3: “DC CHARACTERISTICS: PIC12F519 (Industrial, Extended)”				
Param No.	Sym.	Characteristic	Min.	Typ ⁽¹⁾	Max.	Units	Conditions
43	T _{DW}	Flash Data Memory Write Cycle Time	2	3.5	5	ms	
44	T _{DE}	Flash Data Memory Erase Cycle Time	2	3	4	ms	

* These parameters are characterized but not tested.

Note 1: Data in the Typical (“Typ”) column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

12.0 DC AND AC CHARACTERISTICS GRAPHS AND CHARTS

The graphs and tables provided in this section are for **design guidance** and are **not tested**.

In some graphs or tables, the data presented are **outside specified operating range** (i.e., outside specified V_{DD} range). This is for **information only** and devices are ensured to operate properly only within the specified range.

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore, outside the warranted range.

“Typical” represents the mean of the distribution at 25°C. “Maximum” or “minimum” represents (mean + 3 σ) or (mean - 3 σ) respectively, where σ is a standard deviation, over each temperature range.

FIGURE 12-1: TYPICAL I_{DD} vs. F_{osc} OVER V_{DD} (XT, EXTRC mode)

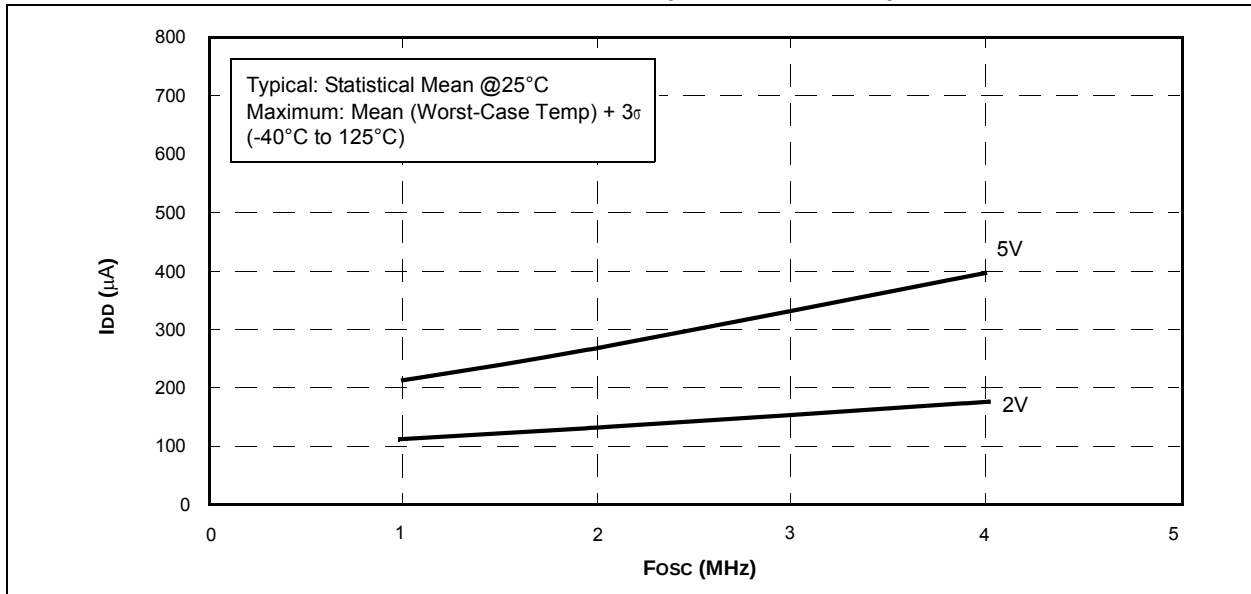
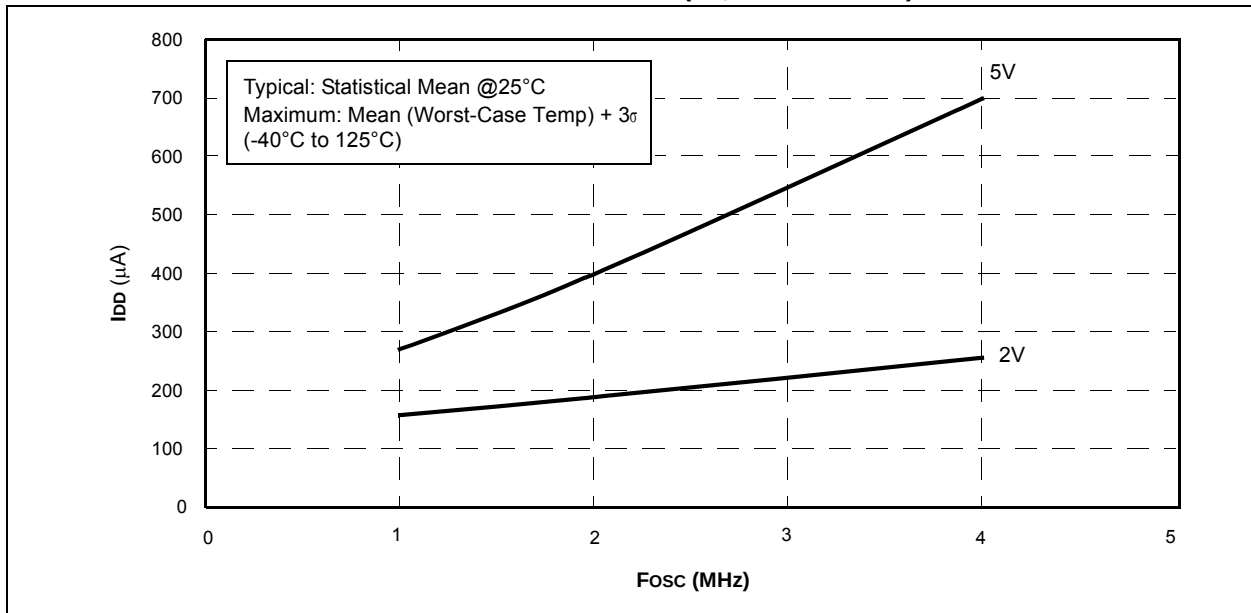


FIGURE 12-2: MAXIMUM I_{DD} vs. F_{osc} OVER V_{DD} (XT, EXTRC mode)



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FIGURE 12-10: V_{OL} vs. I_{OL} OVER TEMPERATURE ($V_{DD} = 5.0V$)

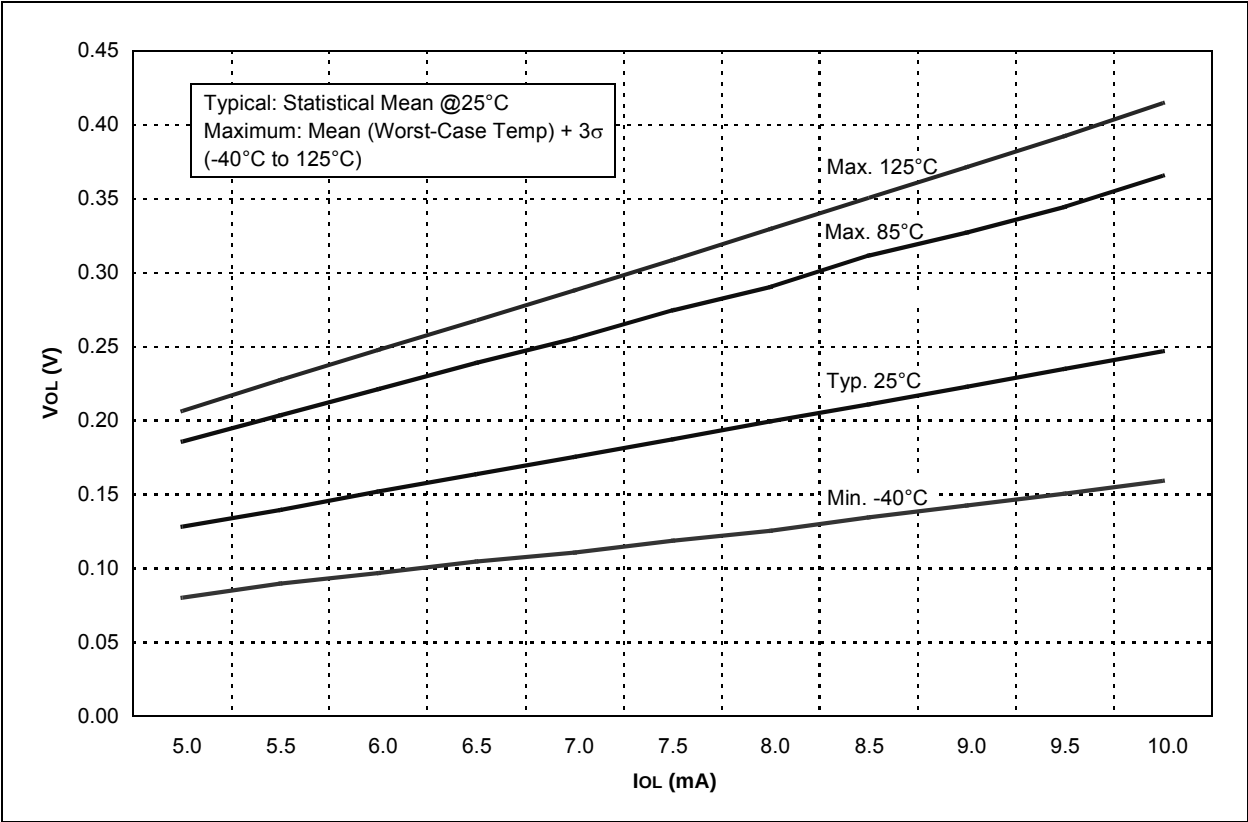
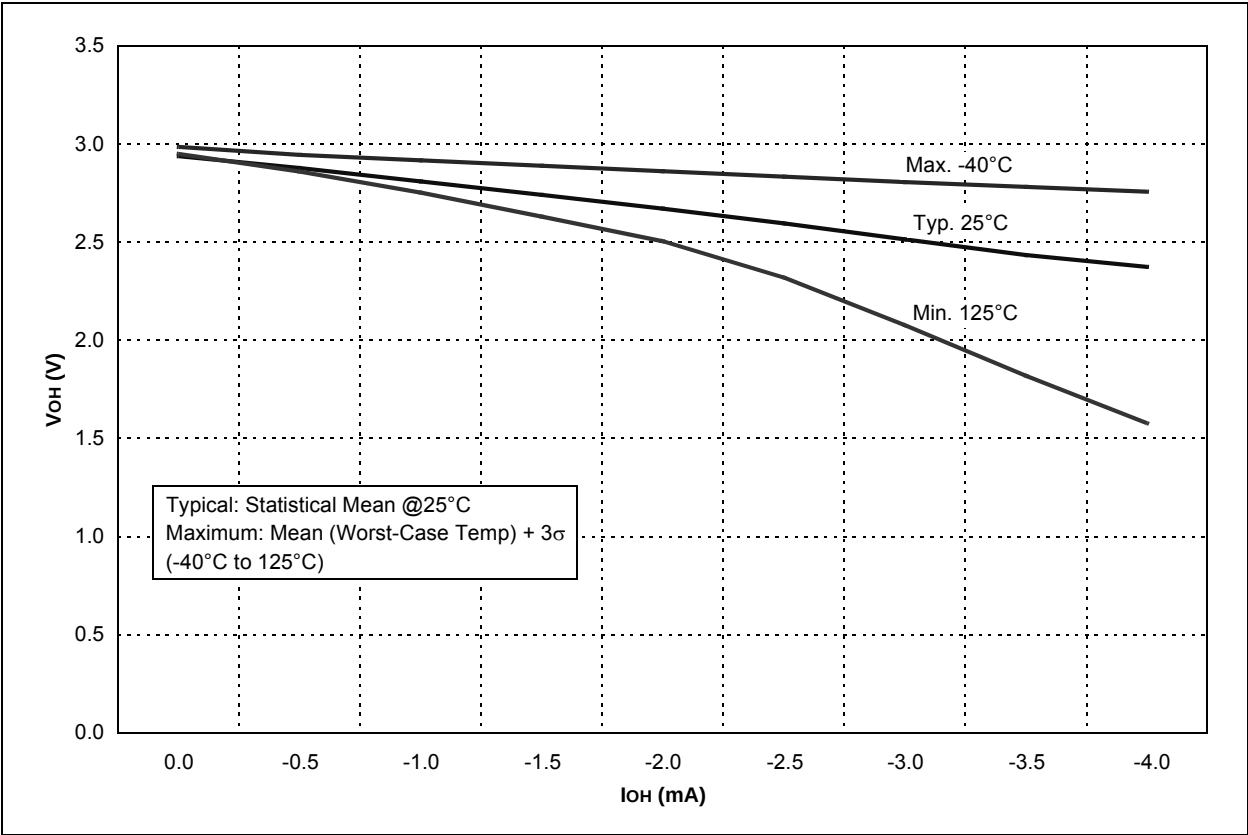
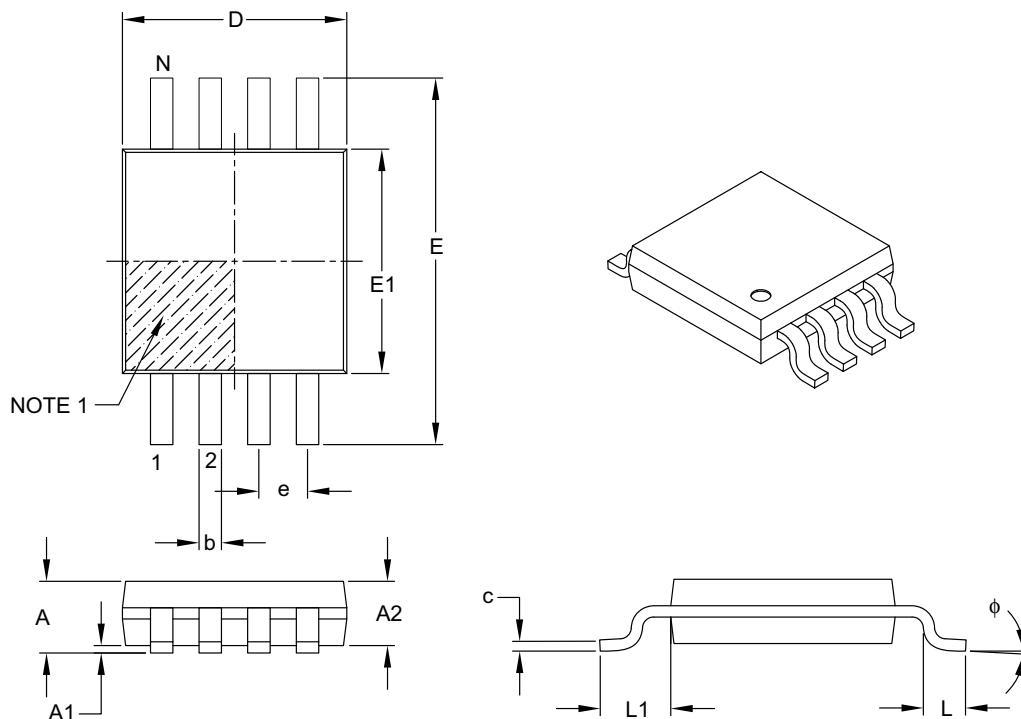


FIGURE 12-11: V_{OH} vs. I_{OH} OVER TEMPERATURE ($V_{DD} = 3.0V$)



8-Lead Plastic Micro Small Outline Package (MS) [MSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N	8		
Pitch	e	0.65 BSC		
Overall Height	A	–	–	1.10
Molded Package Thickness	A2	0.75	0.85	0.95
Standoff	A1	0.00	–	0.15
Overall Width	E	4.90 BSC		
Molded Package Width	E1	3.00 BSC		
Overall Length	D	3.00 BSC		
Foot Length	L	0.40	0.60	0.80
Footprint	L1	0.95 REF		
Foot Angle	φ	0°	–	8°
Lead Thickness	c	0.08	–	0.23
Lead Width	b	0.22	–	0.40

Notes:

- Pin 1 visual index feature may vary, but must be located within the hatched area.
- Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15 mm per side.
- Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-111B

APPENDIX A: REVISION HISTORY

Revision A (May 2007)

Original release of this document.

Revision B (September 2008)

Added DC and AC Characteristics graphs; Updated Electrical Characteristics section; Updated Package Drawings and made general edits.

PIC12F519

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PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

<u>PART NO.</u>	<u>X</u>	<u>/XX</u>	<u>XXX</u>
Device	Temperature Range	Package	Pattern
Device:	PIC12F519 PIC12F519T (Tape and Reel)		
Temperature Range:	I = -40°C to +85°C (Industrial) E = -40°C to +125°C (Extended)		
Package:	MC = 8L DFN 2x3 (DUAL Flatpack No-Leads) MS = MSOP (Pb-free) P = 300 mil PDIP (Pb-free) SN = 3.90 mm SOIC, 8-LD (Pb-free)		
Pattern:	Special Requirements		
Note:	Tape and Reel available for only the following packages: SOIC, DFN and MSOP.		

Examples:
a) PIC12F519-I/P = Industrial temp., PDIP package (Pb-free)
b) PIC12F519T-I/SN = Tape and Reel, Industrial temp., SOIC package
c) PIC12F519 - E/MS 303 = Extended temp., MSOP package, QTP pattern #303